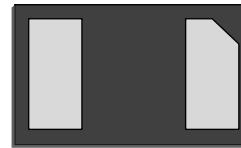


## Features

- Small Body Outline Dimensions:  
0.039" x 0.024" (1.0 mm x 0.60 mm)
- Protects one I/O or power line
- Low Clamping Voltage
- Ultra Low Capacitance: 0.5pF
- Working Voltage: 5 V
- Low Leakage Current
- Response Time is Typically < 1 ns

**DFN-2L**

## IEC COMPATIBILITY (EN61000-4)

- IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)

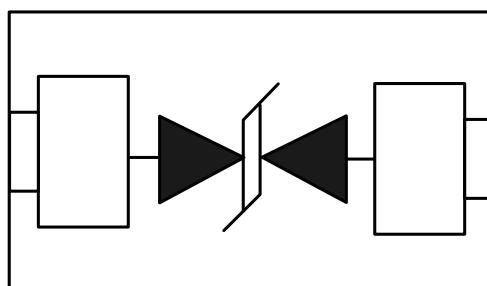
## Mechanical Characteristics

- DFN-2L package
- Molding compound flammability rating:  
UL 94V-0
- Marking: 5T
- Packaging: Tape and Reel per EIA  
481
- RoHS/WEEE Compliant

## Applications

- Laptop Computers
- Cellular Phones
- Digital Cameras
- Personal Digital Assistants (PDAs)

## Schematic & PIN Configuration

**DFN-2L (Top View)**

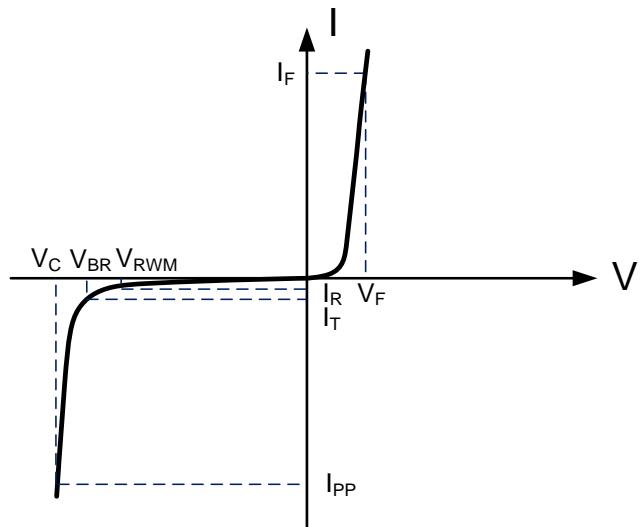


### Absolute Maximum Rating

Rating	Symbol	Value	Units
Electrostatic discharge Voltage (See Note1 ,2)	$V_{ESD}$	8KV (contact)	Volts
		15KV (air)	
Operating Temperature	$T_J$	-55 to + 125	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C

### Electrical Parameters ( $T=25^{\circ}\text{C}$ )

Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$



### Electrical Characteristics

MDFN2C051U						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	$V_{RWM}$				5.0	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T=1\text{mA}$	6.0			V
Reverse Leakage Current	$I_R$	$V_{RWM}=5\text{V}, T=25^{\circ}\text{C}$			1	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP}=1\text{A}, t_p=8/20\mu\text{s}$		8.5	12.5	V
Junction Capacitance	$C_j$	$V_R = 0\text{V}, f = 1\text{MHz}$		0.5		pF

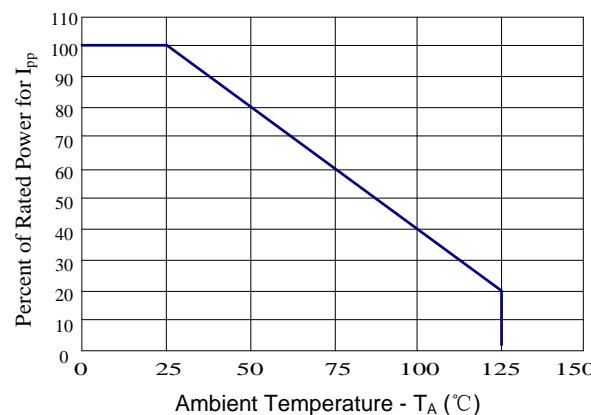
Note1: ESD Pulse Waveform according to IEC 61000-4-2. see Table1 and Figure4.

Note2: ESD tests Setup see Figure 5.

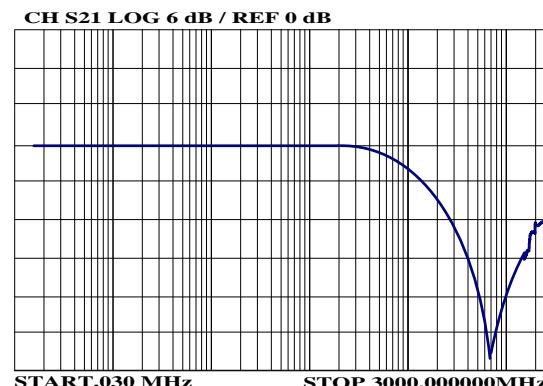


## Typical Characteristics

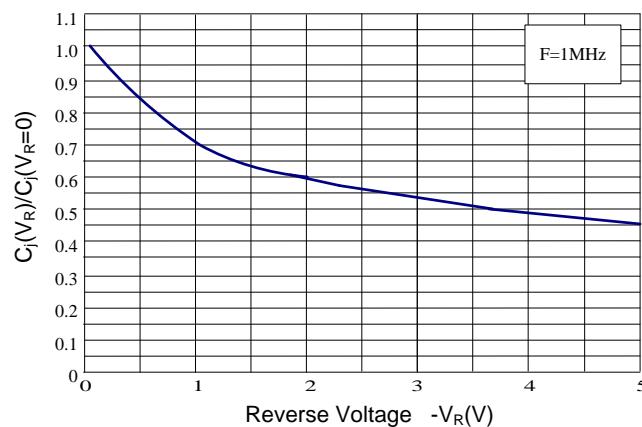
**Figure 1: Power Derating Curve**



**Figure 2: Insertion Loss**



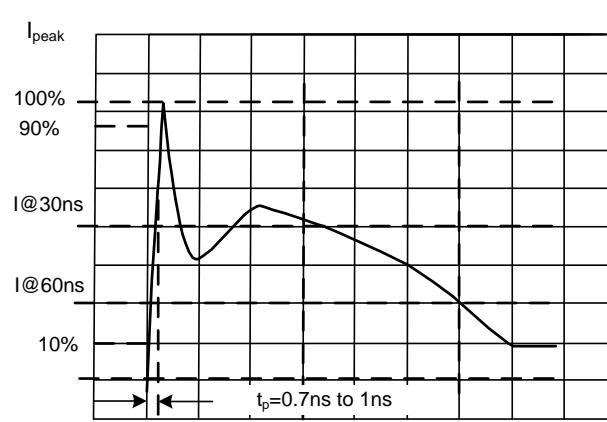
**Figure 3: Normalized Junction Capacitance vs. Reverse Voltage**



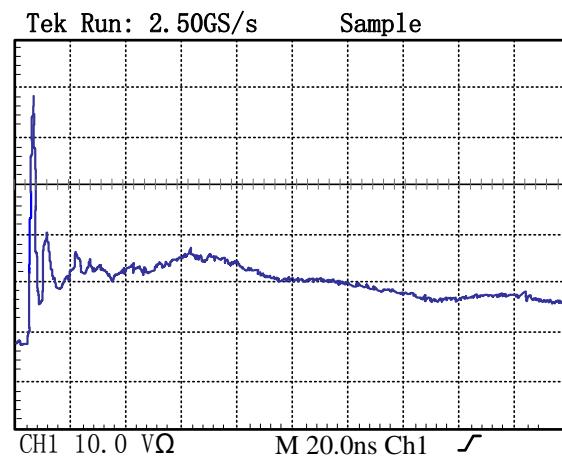
**Table 1. IEC 61000-4-2 Discharge Parameters**

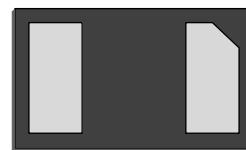
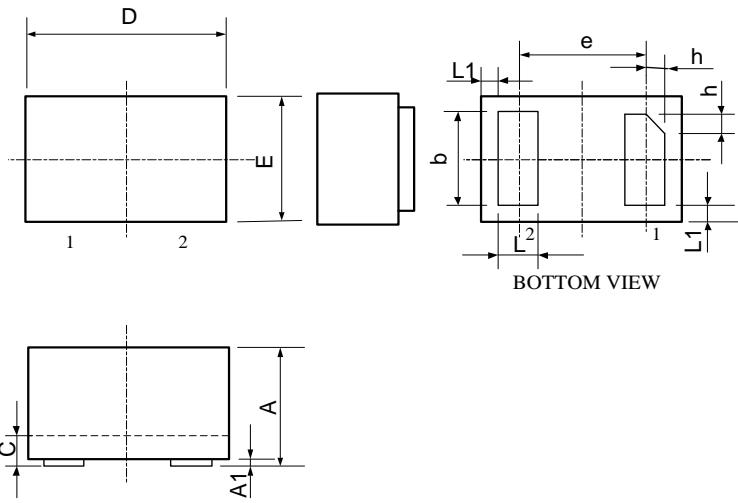
Level	First Peak Current (A)	Peak Current at 30 ns (A)	Peak Current at 60 ns (A)	Test Voltage (Contact Discharge) (kV)	Test Voltage (Air Discharge) (kV)
1	7.5	4	2	2	2
2	15	8	4	4	4
3	22.5	12	6	6	8
4	30	16	8	8	15

**Figure 4. IEC 61000-4-2 Waveform**

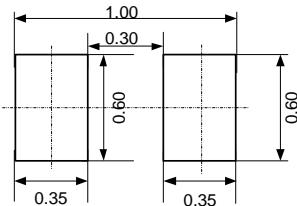


**Figure 5: ESD Clamping( 8kV Contact per IEC 61000-4-2)**



**Outline Drawing –DFN-2L****PACKAGE OUTLINE****DFN-2L**

SYMB	MILIMETER			
	OL	MIN	NOM	MAX
A	0.45	0.50	0.55	
A1	0	0.02	0.05	
b	0.45	0.50	0.55	
C	0.12	0.15	0.18	
D	0.95	1.00	1.05	
e	0.65BSC			
E	0.55	0.60	0.65	
L	0.20	0.25	0.30	
L1	0.05REF			
h	0.07	0.12	0.17	

**Land Pattern**

# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

***Click to view similar products for ESD Suppressors / TVS Diodes category:***

***Click to view products by Me-TECH manufacturer:***

Other Similar products are found below :

[60KS200C](#) [D18V0L1B2LP-7B](#) [D5V0F4U5P5-7](#) [DESD5V0U1BB-7](#) [NTE4902](#) [P4KE27CA](#) [P6KE11CA](#) [P6KE39CA-TP](#) [P6KE8.2A](#)  
[SA110CA](#) [SA60CA](#) [SA64CA](#) [SMBJ12CATR](#) [SMBJ33CATR](#) [SMBJ8.0A](#) [ESD101-B1-02ELS](#) [E6327](#) [ESD105-B1-02EL](#) [E6327](#) [ESD112-B1-02EL](#) [E6327](#) [ESD119B1W01005E6327XTSA1](#) [ESD5V0L1B02VH6327XTSA1](#) [ESD7451N2T5G](#) [19180-510](#) [CPDT-5V0USP-HF](#)  
[3.0SMCJ33CA-F](#) [3.0SMCJ36A-F](#) [HSPC16701B02TP](#) [D3V3Q1B2DLP3-7](#) [D55V0M1B2WS-7](#) [DESD5V0U1BL-7B](#) [DRTR5V0U4SL-7](#)  
[SCM1293A-04SO](#) [ESD200-B1-CSP0201](#) [E6327](#) [SM12-7](#) [SMLJ45CA-TP](#) [CEN955 W/DATA](#) [82350120560](#) [VESD12A1A-HD1-GS08](#)  
[CPDUR5V0R-HF](#) [CPDQC5V0U-HF](#) [CPDQC5V0USP-HF](#) [CPDQC5V0-HF](#) [D1213A-01LP4-7B](#) [D1213A-02WL-7](#) [MMAD1108/TR13](#)  
[5KP100A](#) [5KP15A](#) [5KP18A](#) [5KP48A](#) [5KP90A](#) [5KP90CA](#)